

Substitute for form 1449A/B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known	
				Application Number	Not Yet Assigned
				Filing Date	Concurrently Herewith
				First Named Inventor	Katherine L. Saenger et al.
				Art Unit	N/A
				Examiner Name	Not Yet Assigned
				Attorney Docket Number	YOR920030376US1 CBLH/20140-00312-US1
Sheet	1	of	1		

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
AKS	AA	US-6,188,120	02-13-2001	Andricacos, et al.	
AKS	AB	US-6,391,773	05-21-2002	Andricacos, et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials *	Cite No. ¹	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ²
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)	MM-DD-YYYY			

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NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.		T ²
AKS	CA	MISRA, ET AL., "Electrical properties of Ru-based alloy gate electrodes for dual metal gate Si-CMOS", <i>IEEE Electron Device Letters</i> 23 354 (2002)		
AKS	CB	ZHONG, ET AL., "Properties of Ru-Ta Alloys as Gate Electrodes for NMOS and PMOS Silicon Devices". <i>IDEM</i> 01 467 (2001)		

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Examiner Signature	Ashe Kumar Samkar	Date Considered	4/11/05
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